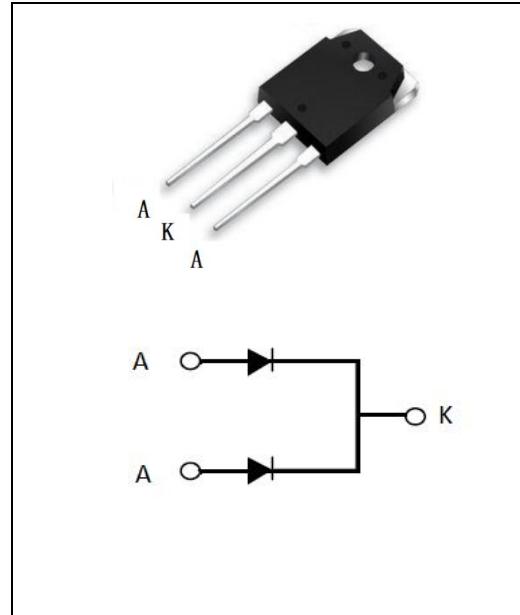


SCHOTTKY RECTIFIERS**Features:**

- High ESD capacity
- High junction temperature capability
- High frequency operation
- Low leakage current
- High surge capacity

Applications:

- Switching mode power supply
- High frequency inverter circuit
- Polarity protection circuit

**Product Summary**

V_R	150 V
$I_F(AV)$	2*15A
T_j	150°C
$V_F(\text{max.})$	0.850V

Absolute Maximum Ratings

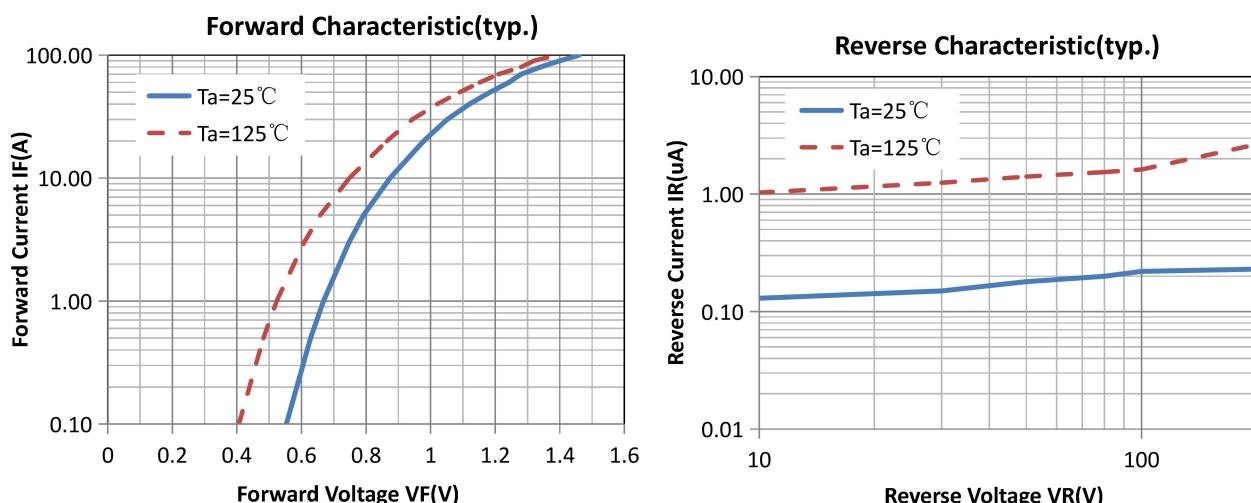
Parameter	Symbol	Values	Units
Repetitive peak reverse voltage	V_{RRM}	150	V
Continuous forward current	$I_F(AV)$	30	A
Single pulse forward current	I_{FSM}	150	
Operating junction	T_j	150	°C
Storage temperatures	T_{stg}	-55 to +150	°C
Peak Repetitive Reverse Surge Current	I_{RRM}	10	A

Electrical characteristics (Ta=25°C unless otherwise specified)						
Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V _{BR} , V _R	I _R =100μA	150			V
Forward voltage (Per Diode)	V _F	I _F =15A		0.9	1.2	
		I _F =15 A, T _j =85°C		0.8	1.1	
Reverse leakage current(Per Diode)	I _R	V _R = V _{RRM}			20	μA
		T _j =125°C , V _R =150V			10	mA

Thermal characteristics

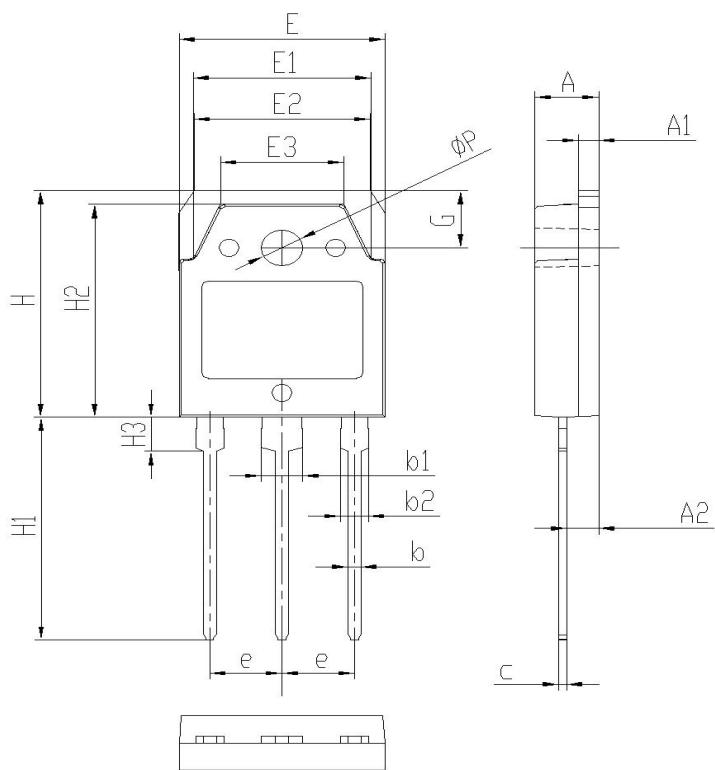
Parameter	Symbol	Typ.	Units
Junction-to-Case	R _{θJC}	0.8	°C /W

Electrical performance (typic)



Package Information

TO-3PB PACKAGE



Symbol	UNIT mm		
	Min	Typ	Max
A	4.60	4.80	5.00
A1	1.3	1.5	1.7
A2	2.20	2.40	2.60
b	0.80	1.0	1.20
b1	2.90	3.10	3.30
b2	1.80	2.00	2.20
c	0.50	0.60	0.70
e	5.25	5.45	5.65
E	15.2	15.6	16.0
E1	13.2	13.4	13.6
E2	15.1	15.3	16.5
E3	9.1	9.3	9.5
H	19.8	20.0	20.2
H1	19.0	19.5	20.0
H2	18.3	18.5	18.7
H3	2.8	3.0	3.2
G	4.8	5.0	5.2
ΦP	3.00	3.20	3.40